

FABRICATION OF BISMUTH SULFIDE THIN FILMS USING L-CYSTEINE AS A NOVEL SULFUR SOURCE

Aistis Melnikas¹, Skirma Žalenkienė¹

¹Kaunas University of Technology, Department of Physical and Inorganic Chemistry, Kaunas, Lithuania
aistis.melnikas@ktu.edu

Bismuth sulfide (Bi_2S_3) thin films have recently attracted considerable attention, due to their suitable optical and electro-optical properties for the use in optoelectronic devices. Bi_2S_3 is a non-toxic, earth-abundant n-type semiconductor with a tunable band gap between 1.3 and 2.2 eV and a high absorption coefficient of 10^5 cm^{-1} [1]. It serves as an industrially available and environmentally friendly alternative n-type layer for the use in photovoltaic applications.

In our research, we investigate the chemical bath deposition method to fabricate FTO (fluorine doped tin oxide) glass substrates by using L-cysteine as a sulfur source. L-cysteine is a simple and promising, yet underexplored sulfur precursor, hence why it is chosen as a novel sulfur source in this experiment. Firstly, $\text{Bi}(\text{NO}_3)_3 \cdot 5\text{H}_2\text{O}$ was dissolved in 1 M nitric acid and diluted with distilled water to obtain a 0.1 mol/L solution. Secondly, a 0.025 mol/L solution of EDTA-Na_2 was added, thoroughly mixed, and heated to 80 °C. EDTA-Na_2 acts as a chelating agent, coordinating to bismuth ions to make the reaction slower, hence making the final Bi_2S_3 nuclei better dispersed [2]. Once the solution reached the optimal temperature, L-cysteine was added and mixed thoroughly. FTO glass substrates were subsequently immersed and kept for 8 h at 80 °C to form thin Bi_2S_3 films. The obtained samples were cleaned with distilled water and annealed in an inert atmosphere.

All samples were analyzed by UV-Vis absorption spectroscopy and X-ray diffraction (XRD) analysis on the Bruker D8 Advance diffractometer. Thin films were scanned over the range $2\theta = 3\text{--}70^\circ$ at a scanning speed of 1° min^{-1} using a coupled two theta/theta scan type. This test determined structural characterization of the obtained materials. Results were studied and compared.

[1] T. O. Ajiboye and D. C. Onwudiwe, "Bismuth sulfide based compounds: Properties, synthesis and applications," *Results in Chemistry*, vol. 3, p. 100151, Jan. 2021, doi: 10.1016/j.rechem.2021.100151.
[2] J. Jiang, G. Gao, R. Yu, G. Qiu, and X. Liu, "Chrysanthemum-like bismuth sulfide microcrystals: Synthesis, characterization, and properties," *Solid State Sciences*, vol. 13, no. 2, pp. 356–360, Dec. 2010, doi: 10.1016/j.solidstatesciences.2010.11.035.